

**CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)**

Applicant(s): Chan et al

Docket No.

YO998426DIV

Serial No.  
10/051,562Filing Date  
January 18, 2002Examiner  
Novacek, Christy L.Group Art Unit  
2822Invention: SELF-ALIGNED COUPLE-GATE MOSFET BY SELECTIVE EPITAXY AND SILICON WAFER  
BONDING TECHNIQUES**RECEIVED  
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FEB 03 2004

**OFFICIAL**I hereby certify that this Amendment Under 37 C.F.R. 1.111  
(Identify type of correspondence)is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. 703-872-9306)on February 3, 2004  
(Date)Frederick W. Gibb, III

(Typed or Printed Name of Person Signing Certificate)

(Signature)

Note: Each paper must have its own certificate of mailing.

10/051,562

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Chan et al.

Serial No.: 10/051,562

Group Art Unit: 2822

Filed: January 18, 2002

Examiner: Novacek, Christy L.

For: SELF-ALIGNED DOUBLE-GATE MOSFET BY SELECTIVE EPITAXY AND  
SILICON WAFER BONDING TECHNIQUES

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT UNDER 37 C.F.R. §1.111**

Sir:

In response to the Office Action mailed November 4, 2003, please amend the above-identified patent application as follows:

**IN THE CLAIMS:**

Please amend the claims as follows.